30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV_{DSS}	Max $R_{DS(on)}$ MAX	Max I_D MAX T_A = 25°C
30V	65mΩ @ V_{GS} = 10V	3.2A
	95mΩ @ V_{GS} = 4.5V	2.6A

Features and Benefits

- Low on-resistance
- Fast switching speed
- Low gate charge
- Low threshold
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Description and Applications

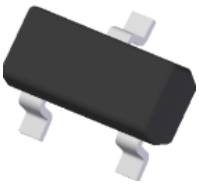
This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC - DC Converters
- Power Management Functions
- Disconnect Switches
- Motor Control

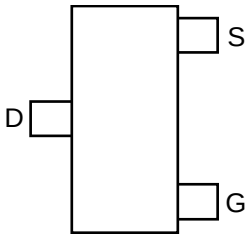
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish —Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)

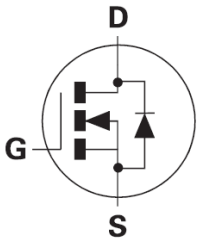
SOT23



Top View



Top View
Pin Out



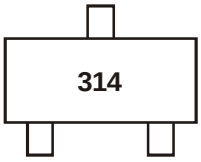
Equivalent Circuit

Ordering Information (Note 5)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMN3A14FQTA	314	7	8	3,000 Units

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.htmlfor more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



314 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

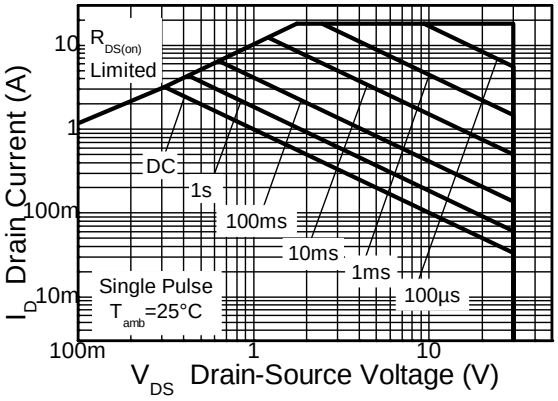
Characteristic				Symbol	Value	Units
Drain-Source Voltage				V_{DSS}	30	V
Gate-Source Voltage				V_{GS}	±20	V
Continuous Drain Current	V_{GS} = 10V	T_A = 70°C	(Note 7) (Note 7) (Note 6)	I_D	3.9 3.2 3.2	A
Pulsed Drain Current (Note 8)				I_{DM}	18	A
Continuous Source Current (Body Diode) (Note 7)				I_S	2.3	A
Pulsed Source Current (Body Diode) (Note 8)				I_{SM}	18	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

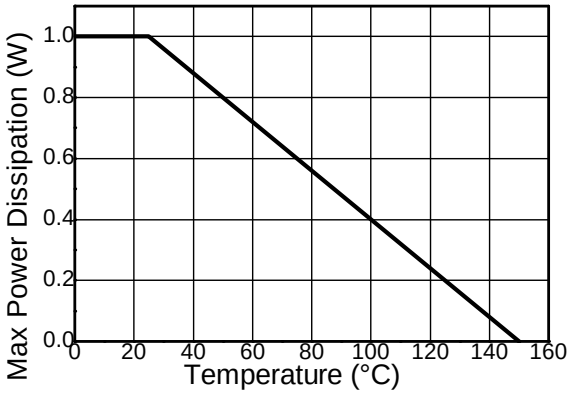
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) Linear Derating Factor	P_D	1 8	W mW/°C
Power Dissipation (Note 7) Linear Derating Factor	P_D	1.5 12	W mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	$R_{\theta JA}$	83	°C/W
Thermal Resistance, Junction to Leads (Note 9)	$R_{\theta JL}$	70.44	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes:
6. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions
7. For a device surface mounted on FR4 PCB measured at t ≤5 secs.
8. Repetitive rating 25mm x 25mm FR4 PCB, D=0.02 pulse width=300µs - pulse current limited by maximum junction temperature.
9. Thermal resistance from junction to solder-point (at the end of the drain lead).

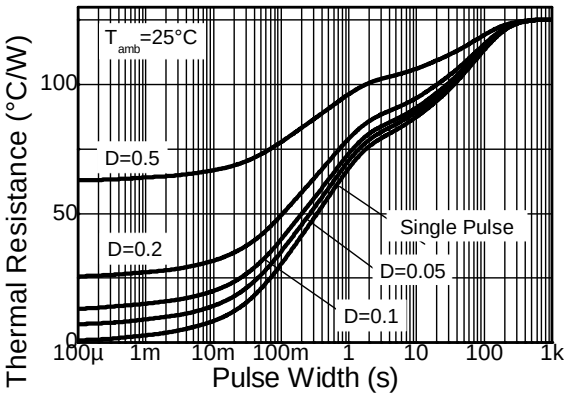
Thermal Characteristics



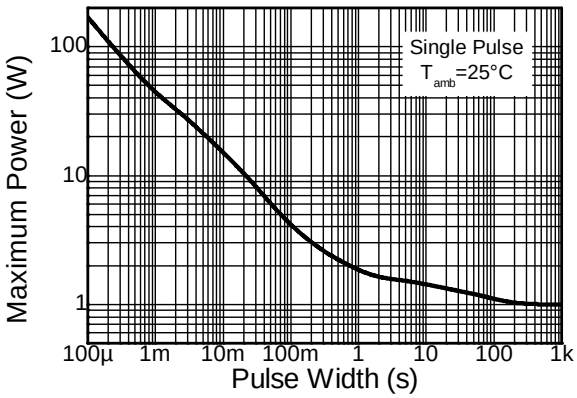
Safe Operating Area



Derating Curve



Transient Thermal Impedance



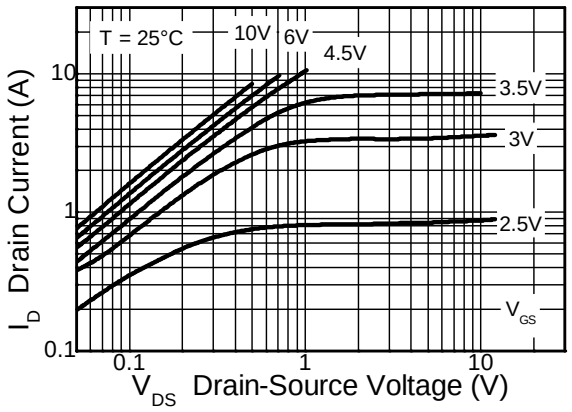
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

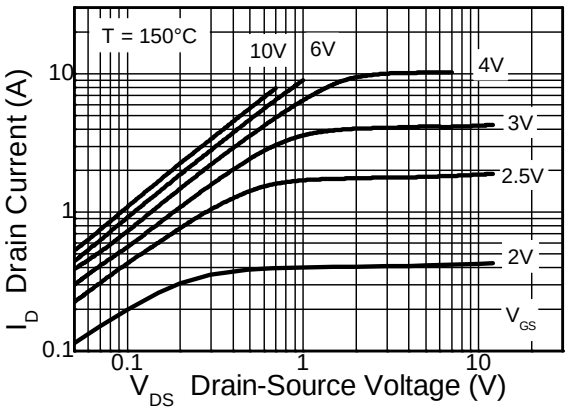
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	30	—	—	V	I_D = 250µA, V_{GS} = 0V
Zero Gate Voltage Drain Current	I_{DSS}	—	—	1	µA	V_{DS} = 30V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	—	—	±100	nA	V_{GS} = ±12V, V_{DS} = 0V
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(th)}$	1.0	—	2.2	V	I_D = 250µA, V_{DS} = V_{GS}
Static Drain-Source On-Resistance (Note 10)	$R_{DS\ (ON)}$	—	48	65	mΩ	V_{GS} = 10V, I_D = 3.2A
			69	95		V_{GS} = 4.5V, I_D = 2.6A
Forward Transconductance (Notes 10 and 12)	g_{fs}	—	7.1	—	S	V_{DS} = 15V, I_D = 3.2A
Diode Forward Voltage (Note 10)	V_{SD}	—	0.85	0.95	V	T_J = 25°C, I_S = 2.5A, V_{GS} = 0V
Reverse Recovery Time (Note 12)	t_{rr}	—	13	—	ns	T_J = 25°C, I_F = 1.6A, di/dt = 100A/µs
Reverse Recovery Charge (Note 12)	Q_{rr}	—	7	—	nC	
DYNAMIC CHARACTERISTICS (Note 12)						
Input Capacitance	C_{iss}	—	448	—	pF	V_{DS} = 15V, V_{GS} = 0V f = 1.0MHz
Output Capacitance	C_{oss}	—	82	—		
Reverse Transfer Capacitance	C_{rss}	—	49	—		
Turn-On Delay Time (Note 11)	$t_{D(on)}$	—	2.4	—	ns	V_{DD} = 15V, I_D = 1A, $R_G \cong 6.0\Omega$, V_{GS} = 10V
Turn-On Rise Time (Note 11)	t_r	—	2.5	—		
Turn-Off Delay Time (Note 11)	$t_{D(off)}$	—	13.1	—		
Turn-Off Fall Time (Note 11)	t_f	—	5.3	—		
Total Gate Charge (Note 11)	Q_g	—	8.6	—	nC	V_{DS} =15V, V_{GS} = 10V, I_D = 3.2A
Gate-Source Charge (Note 11)	Q_{gs}	—	1.4	—		
Gate-Drain Charge (Note 11)	Q_{gd}	—	1.8	—		

Notes:
10. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%.
11. Switching characteristics are independent of operating junction temperature.
12. For design aid only, not subject to production testing.

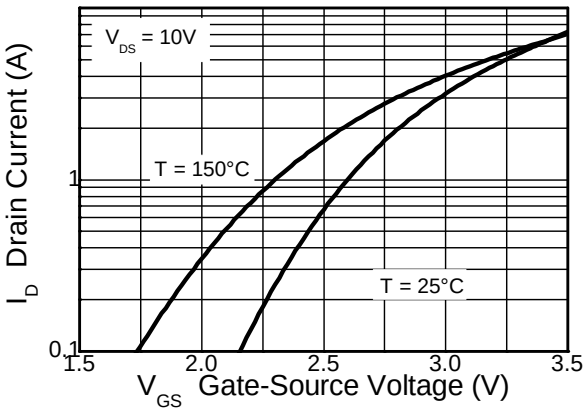
Typical Characteristics



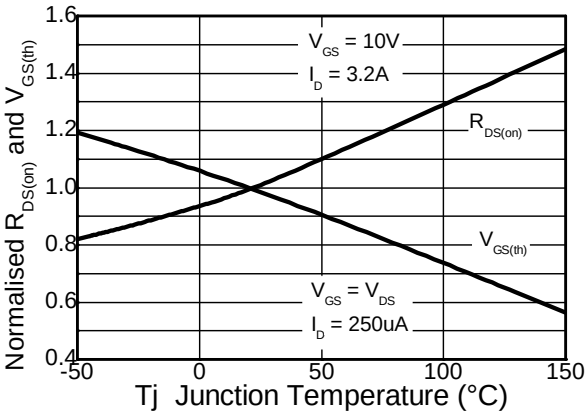
Output Characteristics



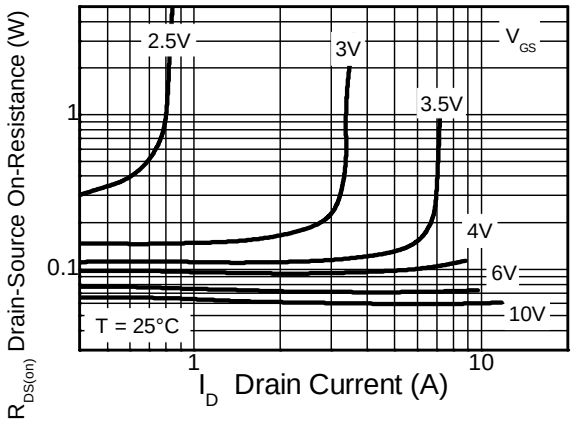
Output Characteristics



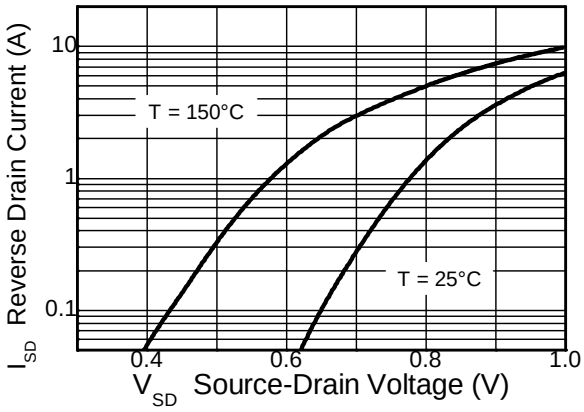
Typical Transfer Characteristics



Normalised Curves v Temperature

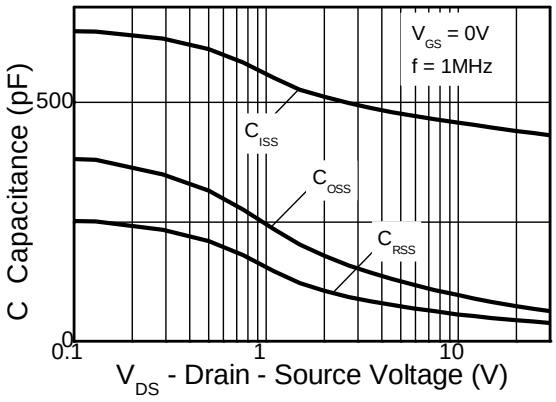


On-Resistance v Drain Current

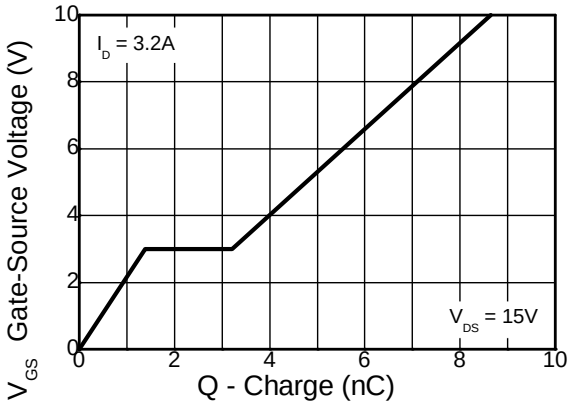


Source-Drain Diode Forward Voltage

Typical Characteristics (continued)

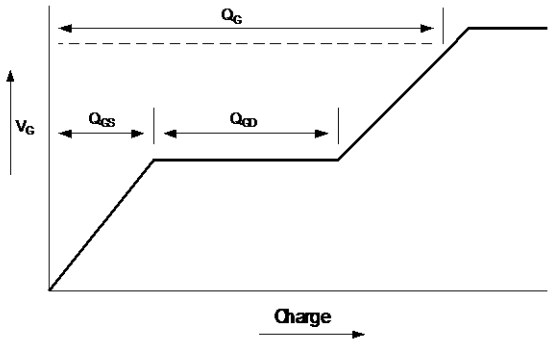


Capacitance v Drain-Source Voltage

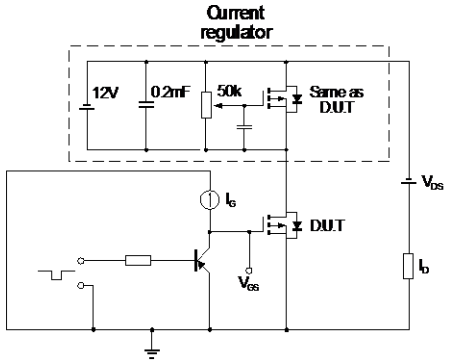


Gate-Source Voltage v Gate Charge

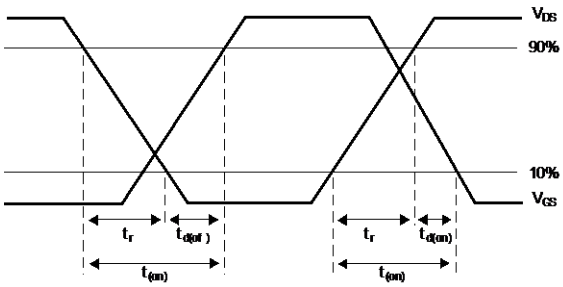
Test Circuits



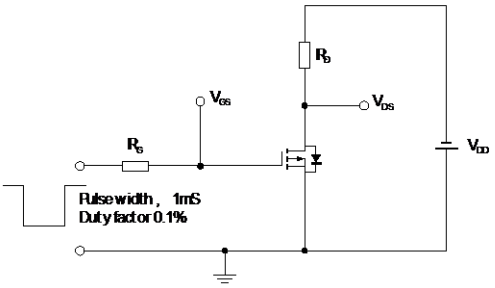
Basic gate charge waveform



Gate charge test circuit



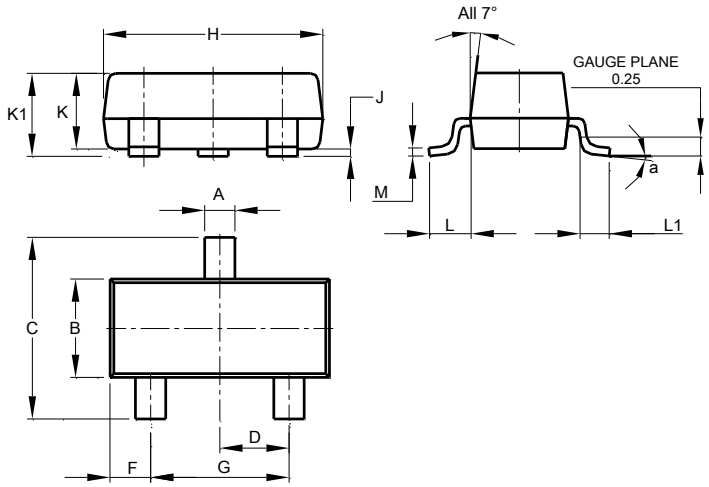
Switching time waveforms



Switching time test circuit

Package Outline Dimensions

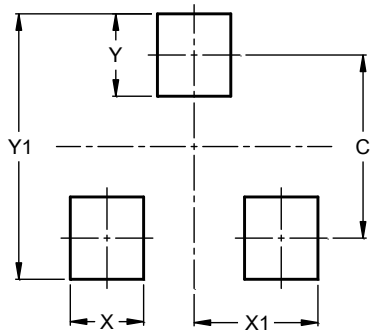
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23			
Dim	**Min**	**Max**	**Typ**
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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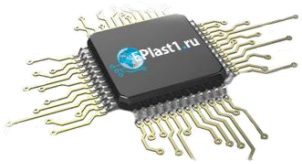
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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